

CMLSH2-4LA
CMLSH2-4LC
CMLSH2-4LS

SURFACE MOUNT SILICON
DUAL PAIR, LOW V_F
SCHOTTKY DIODES



SOT-563 CASE

• Devices are **Halogen Free** by design



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLSH2-4LA series consists of dual pairs of common anode, common cathode, and in-series low V_F Schottky diodes manufactured in an SOT-563 surface mount package.

DEVICE CONFIGURATIONS:

CMLSH2-4LA	DUAL PAIR, COMMON ANODE	MARKING CODE: 4AL
CMLSH2-4LC	DUAL PAIR, COMMON CATHODE	MARKING CODE: 4CL
CMLSH2-4LS	DUAL PAIR, IN SERIES	MARKING CODE: 4SL

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	40	V
Continuous Forward Current	I_F	200	mA
Peak Repetitive Forward Current	I_{FRM}	300	mA
Peak Forward Surge Current, $t_p=10\text{ms}$	I_{FSM}	600	mA
Power Dissipation (Note 1)	P_D	350	mW
Power Dissipation (Note 2)	P_D	300	mW
Power Dissipation (Note 3)	P_D	150	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance (Note 1)	θ_{JA}	357	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS PER DIODE: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_R	$V_R=25\text{V}$		100	500	nA
BV_R	$I_R=100\mu\text{A}$	40	55		V
V_F	$I_F=100\mu\text{A}$		0.24	0.26	V
V_F	$I_F=500\mu\text{A}$		0.29	0.31	V
V_F	$I_F=1.0\text{mA}$		0.31	0.33	V
V_F	$I_F=50\text{mA}$		0.54	0.60	V
V_F	$I_F=100\text{mA}$		0.67	0.75	V
C_J	$V_R=1.0\text{V}, f=1.0\text{MHz}$			10	pF
t_{rr}	$I_F=I_R=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$			5.0	ns

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm^2
(2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm^2
(3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm^2

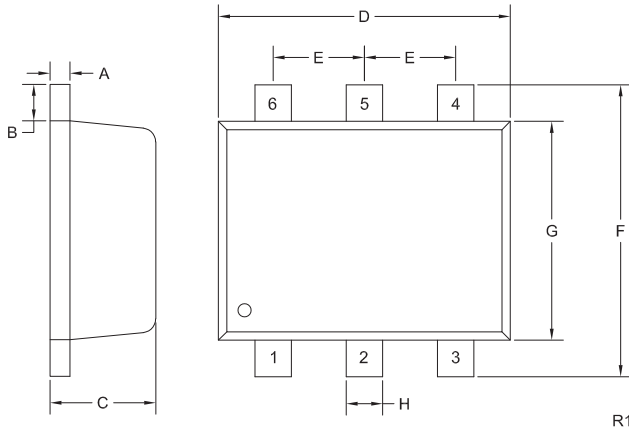
R6 (14-February 2014)

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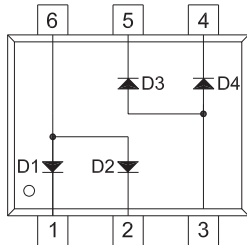
SOT-563 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.0027	0.007	0.07	0.18
B	0.008		0.20	
C	0.017	0.024	0.45	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.061	0.067	1.55	1.70
G	0.045	0.049	1.15	1.25
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R1)

PIN CONFIGURATIONS

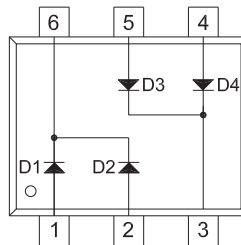


CMLSH2-4LA

LEAD CODE:

- 1) Cathode D1
- 2) Cathode D2
- 3) Anode D3, D4
- 4) Cathode D4
- 5) Cathode D3
- 6) Anode D1, D2

MARKING CODE: 4AL

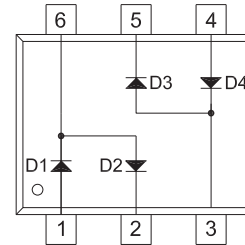


CMLSH2-4LC

LEAD CODE:

- 1) Anode D1
- 2) Anode D2
- 3) Cathode D3, D4
- 4) Anode D4
- 5) Anode D3
- 6) Cathode D1, D2

MARKING CODE: 4CL



CMLSH2-4LS

LEAD CODE:

- 1) Anode D1
- 2) Cathode D2
- 3) Anode D3, Cathode D4
- 4) Anode D4
- 5) Cathode D3
- 6) Cathode D1, Anode D2

MARKING CODE: 4SL

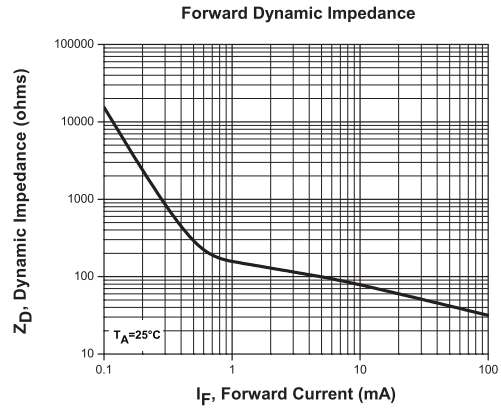
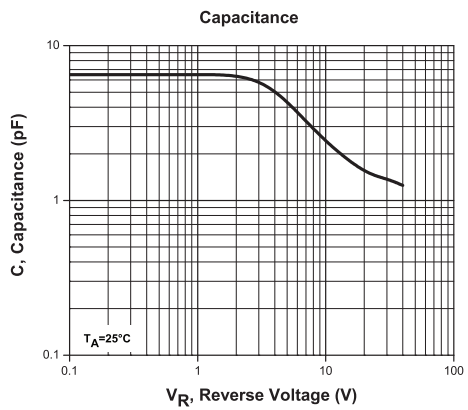
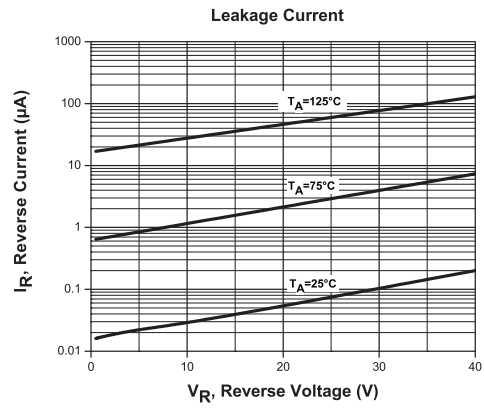
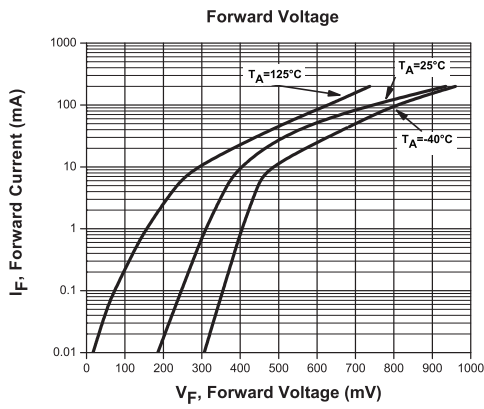
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TYPICAL ELECTRICAL CHARACTERISTICS



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